

Energy

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Innovation for Our Energy Future

Results from the Second International Module Inter-comparison

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History

1987 to 1989 - PEP '87

Cells, cell in module package and module of identical type 2 day meeting of participants, PTB issued formal report, 1990 presented at 21 IEEE PVSC

Range Si Modules; I_{sc} = 2-5%, FF = 1-2%, V_{oc} = 2-5% Range a-Si tandem Modules I_{sc} = 8%, FF = 2.5%, V_{oc} = 1% Final Report analyzed data using 2 standard deviations, I_{sc} 2-6% for Si, 3-10% for a-Si, FF 1-2%, V_{oc} 0-5%

1992 to 1994 - ASTM E1036 Interlaboratory Test Program encapsulated cells provided, (Range in $P_{max} \sim 5\%$) P_{max} 95 % repeatability limit (within laboratory) = 0.7% P_{max} 95 % reproducibility limit (between laboratory) = 6.7%

Manufacture sponsored intercomparisons - often only 2 labs & results usually not published.



Goals

Evaluate differences in module IV parameters With **Respect to Standard Reference Conditions between** National Calibration facilities ISO-17025 Accredited PV **Qualification or Calibration Labs** Modules Chosen to – Identify differences in participants scope Flat-plate, Concentrator Single-junction, Multi-junction Crystalline Si, Thin-film "Typical" Quantum Efficiency supplied by the manufacturer No reference cell is provided Include Samples that have had measurement related problems Bias Rate, Current Matching for Multi-junction, Sensitivity to Spatial Nonuniformity, Tracking for concentrator National Renewable Energy Laboratory

AstroPower S/N#200205740248 7/30/2002

mono-Si

HO AAH

2111

0

0.0

720 kWhrm⁻² of sunlight prior to circulation No significant change in modules during intercomparison except ~3% for amorphus Si



multi-Si

The Sample Set - CdTe & CIGS









Results - P_{max} @ 25 C, 1000 Wm⁻², IEC Global Reference spectrum



Results - I_{sc}





Results - Fill Factor



Results - Voc





Summary

- Range in I_{sc} for Si 5%, CIS 5 & 8%, CdTe 4%, Multijunction range 4 to 19% depending on module. Not having the luxury of a matched reference cell, Representative cell, or the Measured Module spectral responsivity may be the cause of larger differences than previous module intercomparisons.
- Range in P_{max} for Si 6 & 7%, CIS or CdTe 8%, Multijunction range 7 to 17% depending on module.
- Range in V_{oc} for Si 4 to 5%. About an 8 C temperature range would be required to account for a 5% V_{oc} difference.
- Several participants didn't measure concentrator or thinfilm modules because they were outside their scope.

